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## Felicidades al nuevo graduado de doctorado del ICFO

El Dr. Maximilian Heithoff se ha doctorado con una tesis titulada "Exciton engineering for quantum confinement in an electrostatically defined PN-junction"

June 04, 2025

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Felicidades al Dr. Maximilian Heithoff que ha defendido su tesis esta mañana en el Auditorio del ICFO.

El Dr. Heithoff obtuvo su Master en Física por la RWTH Aachen University, antes de unirse al grupo de investigación de Quantum Nano-Optoelectronics dirigido por el profesor ICREA en ICFO el Dr. Frank Koppens. Su tesis titulada "Exciton engineering for quantum confinement in an electrostatically defined PN-junction" ha sido supervisada por el Prof. Dr. Frank Koppens y el Dr. Antoine Reserbat-Plantey.

### **RESUMEN:**

We investigate the physics of quantum-confined excitons in an electrostatically defined PN junction. Such a PN junction can be generated in an encapsulated monolayer  $\text{MoSe}_2$  along the patterned edge of a top-gate electrode. Applying a voltage gradient between the top and bottom gates results in the formation of an in-plane electric-field gradient in the depletion region and strong doping gradients in the P- and N-doped regions of the PN junction. The exciton experiences an attractive force within the electric field gradient and repulsion from exciton-charge carrier interactions. The combined effects are sufficiently strong to quantize the number of available excitonic states within the potential. We show measurements of these quantum-confined excitons in reflection contrast and photoluminescence spectroscopy. We demonstrate how the confinement potential results in fine structure splitting with linearly polarized excitonic states that are aligned either along or perpendicular to the top gate edge. The states can be gradually tuned between linear and circular polarization using an out-of-plane magnetic field. Our particular sample geometry, where the formation of the PN junction electrically isolates the sample from ground, allows us to investigate the electrostatic model of a photo-biased PN junction, with the bias voltage as an additional tuning parameter of the confinement potential. The bias voltage is modified by the measurement itself and varies with the location of the measurement. We demonstrate how the combined impact of exciton dissociation and Auger-assisted hot-hole tunneling modifies the bias voltage over a timescale up to. The bias voltage can be further controlled using a

second laser, which enables the tuning of the energy of the quantized states over the range of. Ultimately, these findings allow us to simulate the exact shape of the confinement potential and to investigate how the in-plane electric field modifies the internal exciton structure, impacting the exciton oscillator strength, lifetime, and dissociation. The results of this thesis illustrate the possibilities to pattern tailored exciton potential shapes for photonic and quantum technologies.

**Tribunal de Tesis:**

Prof. Dr. Niek Van Hulst, ICFO

Prof. Dr. Brian Gerardot, Heriot Watt University

Prof. Dr. Andreas Stier, Walter Schottky Institut